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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Discontinued at Digi-Key |
| Core Processor | RL78 |
| Core Size | 16-Bit |
| Speed | 32MHz |
| Connectivity | CSI, I ² C, LINbus, UART/USART |
| Peripherals | DMA, LVD, POR, PWM, WDT |
| Number of I/O | 21 |
| Program Memory Size | 96KB (96K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 8K x 8 |
| RAM Size | 8K x 8 |
| Voltage - Supply (Vcc/Vdd) | 1.6V ~ 5.5V |
| Data Converters | A/D 8x8/10b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 30-LSSOP (0.240", 6.10mm Width) |
| Supplier Device Package | 30-LSSOP |
| Purchase URL | https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100afdsp-v0 |

Table 1-1. List of Ordering Part Numbers

(3/12)

| Pin count | Package | Data flash | Fields of Application <small>Note</small> | Ordering Part Number |
|-----------|--|-------------|--|---|
| 36 pins | 36-pin plastic WFLGA (4 × 4 mm, 0.5 mm pitch) | Mounted | A | R5F100CAALA#U0, R5F100CCALA#U0, R5F100CDALA#U0, R5F100CEAL#U0, R5F100CFALA#U0, R5F100CGALA#U0 R5F100CAALA#W0, R5F100CCALA#W0, R5F100CDALA#W0, R5F100CEAL#W0, R5F100CFALA#W0, R5F100CGALA#W0 R5F100CAGLA#U0, R5F100CCGLA#U0, R5F100CDGLA#U0, R5F100CEGLA#U0, R5F100CFGGLA#U0, R5F100CGGLA#U0 R5F100CAGLA#W0, R5F100CCGLA#W0, R5F100CDGLA#W0, R5F100CEGLA#W0, R5F100CFGGLA#W0, R5F100CGGLA#W0 |
| | | | G | R5F101CAALA#U0, R5F101CCALA#U0, R5F101CDALA#U0, R5F101CEAL#U0, R5F101CFALA#U0, R5F101CGALA#U0 R5F101CAALA#W0, R5F101CCALA#W0, R5F101CDALA#W0, R5F101CEAL#W0, R5F101CFALA#W0, R5F101CGALA#W0 |
| 40 pins | 40-pin plastic HWQFN (6 × 6 mm, 0.5 mm pitch) | Mounted | A | R5F100EAANA#U0, R5F100ECANA#U0, R5F100EDANA#U0, R5F100EEANA#U0, R5F100EFANA#U0, R5F100EGANA#U0, R5F100EHANA#U0 R5F100EAANA#W0, R5F100ECANA#W0, R5F100EDANA#W0, R5F100EEANA#W0, R5F100EFANA#W0, R5F100EGANA#W0, R5F100EHANA#W0 R5F100EADNA#U0, R5F100ECDNA#U0, R5F100EDDNA#U0, R5F100EEDNA#U0, R5F100EFDNA#U0, R5F100EGDNA#U0, R5F100EHDNA#U0 R5F100EADNA#W0, R5F100ECDNA#W0, R5F100EDDNA#W0, R5F100EEDNA#W0, R5F100EFDNA#W0, R5F100EGDNA#W0, R5F100EHDNA#W0 R5F100EAGNA#U0, R5F100ECGNA#U0, R5F100EDGNA#U0, R5F100EEGNA#U0, R5F100EFGNA#U0, R5F100EGGNA#U0, R5F100EHGNA#U0 R5F100EAGNA#W0, R5F100ECGNA#W0, R5F100EDGNA#W0, R5F100EEGNA#W0, R5F100EFGNA#W0, R5F100EGGNA#W0, R5F100EHGNA#W0 |
| | | | D | R5F100EAANA#U0, R5F100ECANA#U0, R5F100EDANA#U0, R5F100EEANA#U0, R5F100EFANA#U0, R5F100EGANA#U0, R5F100EHANA#U0 R5F100EAANA#W0, R5F100ECANA#W0, R5F100EDANA#W0, R5F100EEANA#W0, R5F100EFANA#W0, R5F100EGANA#W0, R5F100EHANA#W0 R5F100EADNA#U0, R5F100ECDNA#U0, R5F100EDDNA#U0, R5F100EEDNA#U0, R5F100EFDNA#U0, R5F100EGDNA#U0, R5F100EHDNA#U0 R5F100EADNA#W0, R5F100ECDNA#W0, R5F100EDDNA#W0, R5F100EEDNA#W0, R5F100EFDNA#W0, R5F100EGDNA#W0, R5F100EHDNA#W0 |
| | | Not mounted | A | R5F101EAANA#U0, R5F101ECANA#U0, R5F101EDANA#U0, R5F101EEANA#U0, R5F101EFANA#U0, R5F101EGANA#U0, R5F101EHANA#U0 R5F101EAANA#W0, R5F101ECANA#W0, R5F101EDANA#W0, R5F101EEANA#W0, R5F101EFANA#W0, R5F101EGANA#W0, R5F101EHANA#W0 R5F101EADNA#U0, R5F101ECDNA#U0, R5F101EDDNA#U0, R5F101EEDNA#U0, R5F101EFDNA#U0, R5F101EGDNA#U0, R5F101EHDNA#U0 R5F101EADNA#W0, R5F101ECDNA#W0, R5F101EDDNA#W0, R5F101EEDNA#W0, R5F101EFDNA#W0, R5F101EGDNA#W0, R5F101EHDNA#W0 |
| | | | D | R5F101EADNA#U0, R5F101ECDNA#U0, R5F101EDDNA#U0, R5F101EEDNA#U0, R5F101EFDNA#U0, R5F101EGDNA#U0, R5F101EHDNA#U0 R5F101EADNA#W0, R5F101ECDNA#W0, R5F101EDDNA#W0, R5F101EEDNA#W0, R5F101EFDNA#W0, R5F101EGDNA#W0, R5F101EHDNA#W0 |

Note For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

Table 1-1. List of Ordering Part Numbers

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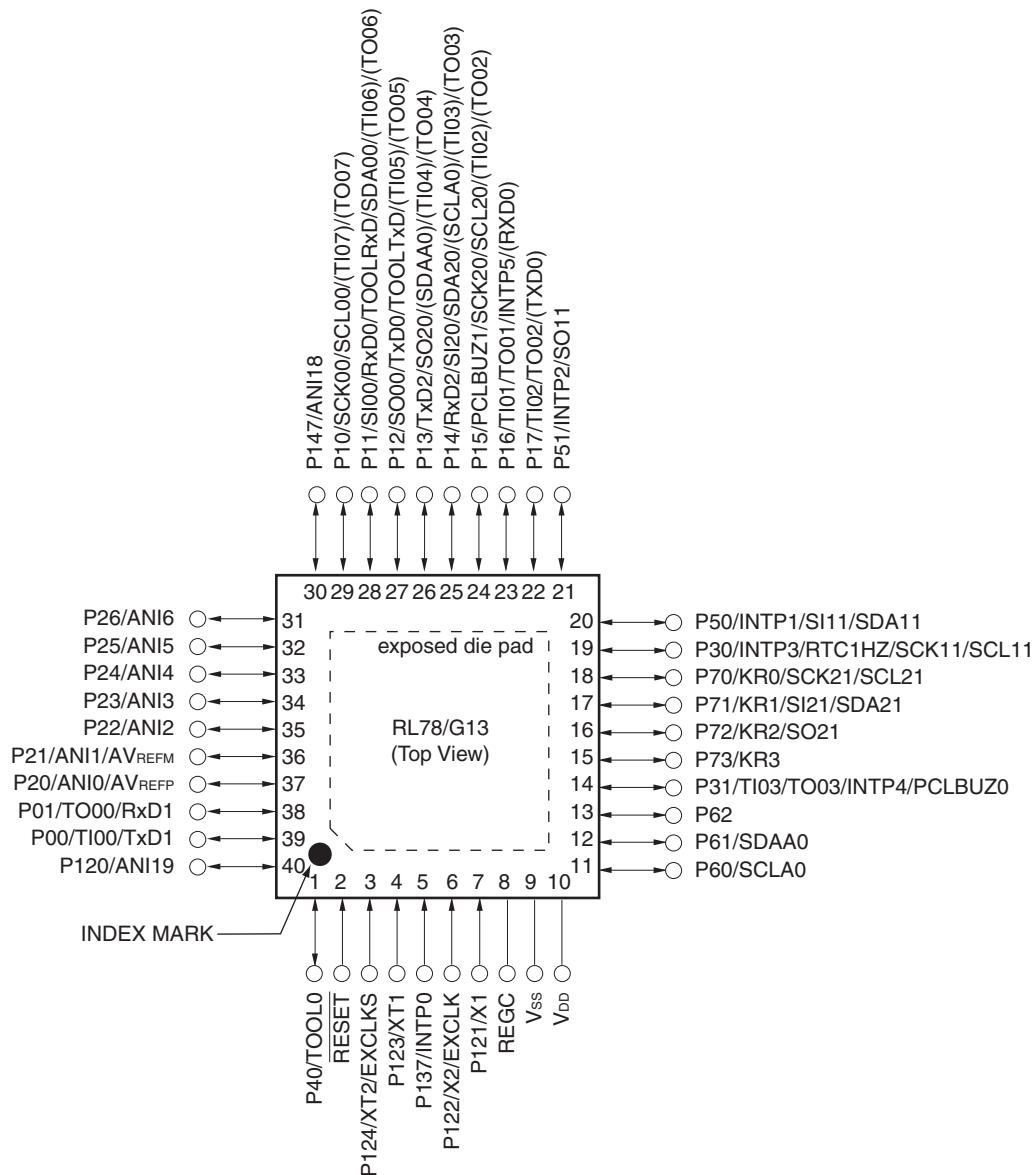
| Pin count | Package | Data flash | Fields of Application <small>Note</small> | Ordering Part Number |
|-----------|---|------------|--|--|
| 52 pins | 52-pin plastic LQFP (10 × 10 mm, 0.65 mm pitch) | Mounted | A | R5F100JCAFA#V0, R5F100JDAFA#V0, R5F100JEAF#V0, R5F100JFAFA#V0, R5F100JGAFA#V0, R5F100JHAFA#V0, R5F100JJFAFA#V0, R5F100JKAFA#V0, R5F100JLAFA#V0 R5F100JCAFA#X0, R5F100JDAFA#X0, R5F100JEAF#X0, R5F100JFAFA#X0, R5F100JGAFA#X0, R5F100JHAFA#X0, R5F100JJFAFA#X0, R5F100JKAFA#X0, R5F100JLAFA#X0 R5F100JCDSA#V0, R5F100JDDFA#V0, R5F100JEDFA#V0, R5F100JFDFA#V0, R5F100JGDFA#V0, R5F100JHDFA#V0, R5F100JJDFA#V0, R5F100JKDFA#V0, R5F100JLDFA#V0 R5F100JCDSA#X0, R5F100JDDFA#X0, R5F100JEDFA#X0, R5F100JFDFA#X0, R5F100JGDFA#X0, R5F100JHDFA#X0, R5F100JJDFA#X0, R5F100JKDFA#X0, R5F100JLDFA#X0 R5F100JCGFA#V0, R5F100JDGFA#V0, R5F100JEGFA#V0, R5F100JFGFA#V0, R5F100JGGFA#V0, R5F100JHGFA#V0, R5F100JJGFA#V0 R5F100JCGFA#X0, R5F100JDGFA#X0, R5F100JEGFA#X0, R5F100JFGFA#X0, R5F100JGGFA#X0, R5F100JHGFA#X0, R5F100JJGFA#X0 |
| | | | D | R5F101JCAFA#V0, R5F101JDAFA#V0, R5F101JEAF#V0, R5F101JFAFA#V0, R5F101JGAFA#V0, R5F101JHAFA#V0, R5F101JJFAFA#V0, R5F101JKAFA#V0, R5F101JLAFA#V0 R5F101JCAFA#X0, R5F101JDAFA#X0, R5F101JEAF#X0, R5F101JFAFA#X0, R5F101JGAFA#X0, R5F101JHAFA#X0, R5F101JJFAFA#X0, R5F101JKAFA#X0, R5F101JLAFA#X0 R5F101JCDSA#V0, R5F101JDDFA#V0, R5F101JEDFA#V0, R5F101JFDFA#V0, R5F101JGDFA#V0, R5F101JHDFA#V0, R5F101JJDFA#V0, R5F101JKDFA#V0, R5F101JLDFA#V0 R5F101JCDSA#X0, R5F101JDDFA#X0, R5F101JEDFA#X0, R5F101JFDFA#X0, R5F101JGDFA#X0, R5F101JHDFA#X0, R5F101JJDFA#X0, R5F101JKDFA#X0, R5F101JLDFA#X0 |

Note For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

1.3.7 40-pin products

- 40-pin plastic HWQFN (6 × 6 mm, 0.5 mm pitch)



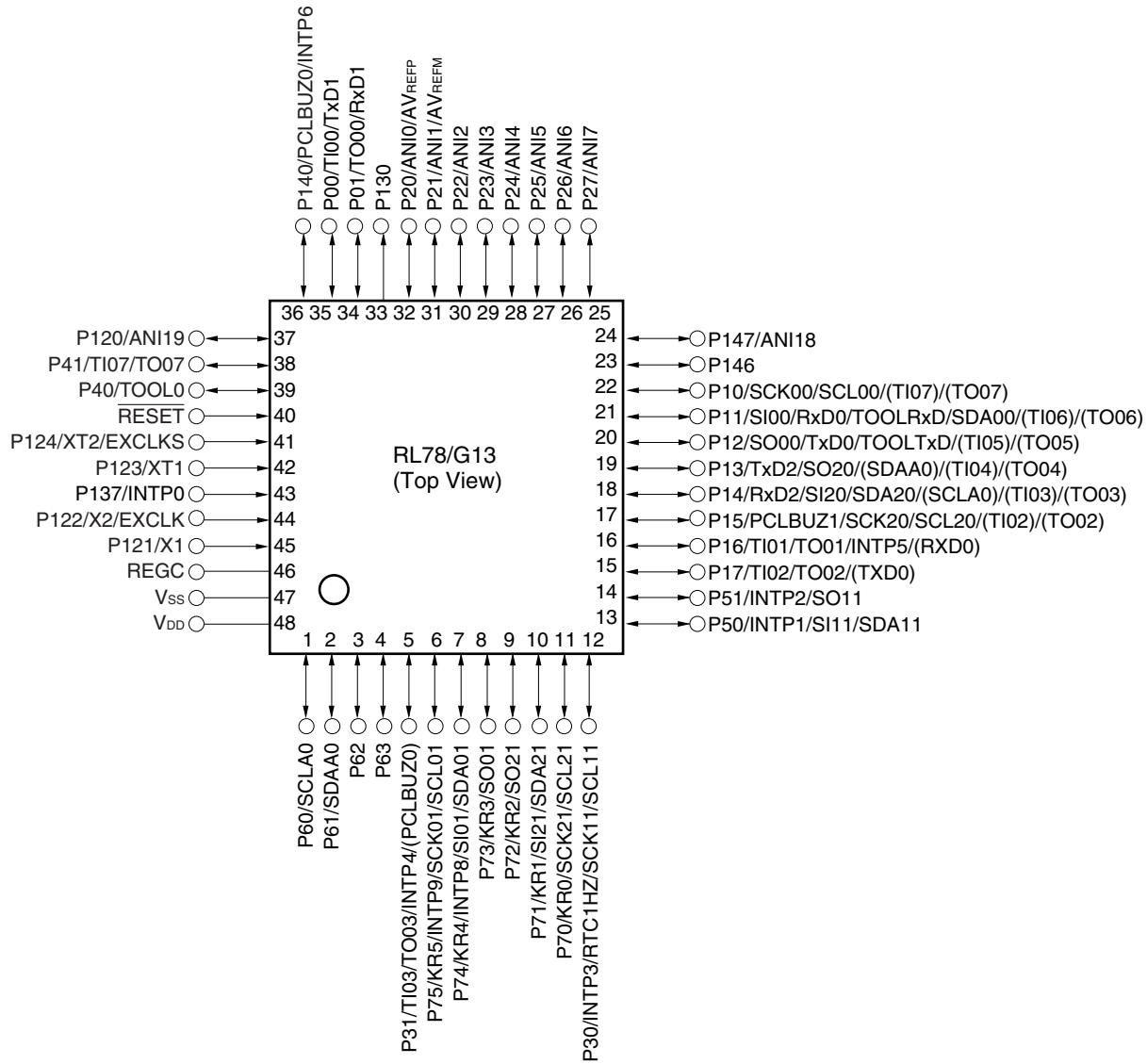
Caution Connect the REGC pin to V_{ss} via a capacitor (0.47 to 1 μ F).

Remarks 1. For pin identification, see **1.4 Pin Identification**.

2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.
3. It is recommended to connect an exposed die pad to V_{ss}.

1.3.9 48-pin products

- 48-pin plastic LFQFP (7 × 7 mm, 0.5 mm pitch)



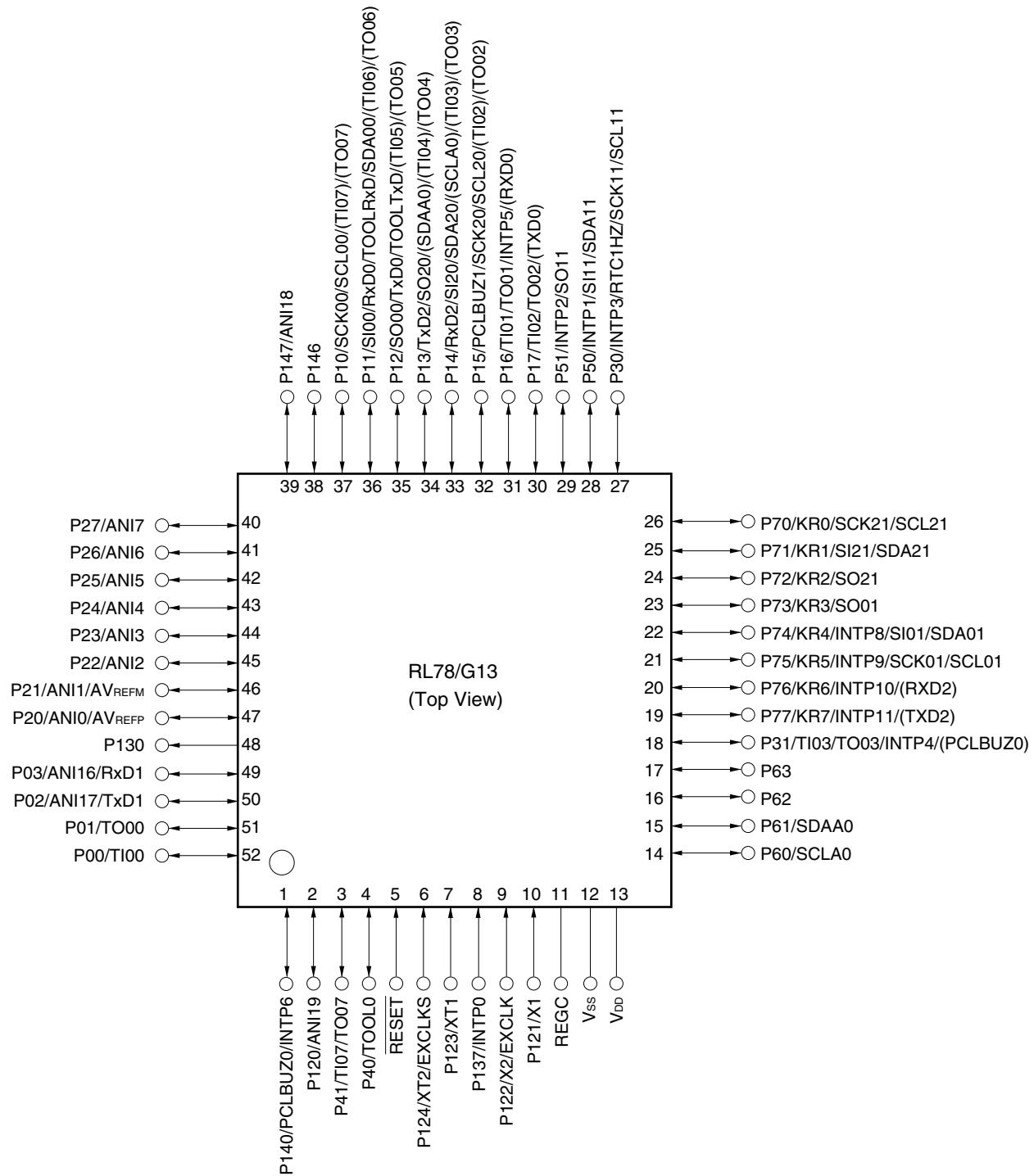
Caution Connect the REGC pin to Vss via a capacitor (0.47 to 1 μ F).

Remarks 1. For pin identification, see **1.4 Pin Identification**.

2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.3.10 52-pin products

- 52-pin plastic LQFP (10 × 10 mm, 0.65 mm pitch)

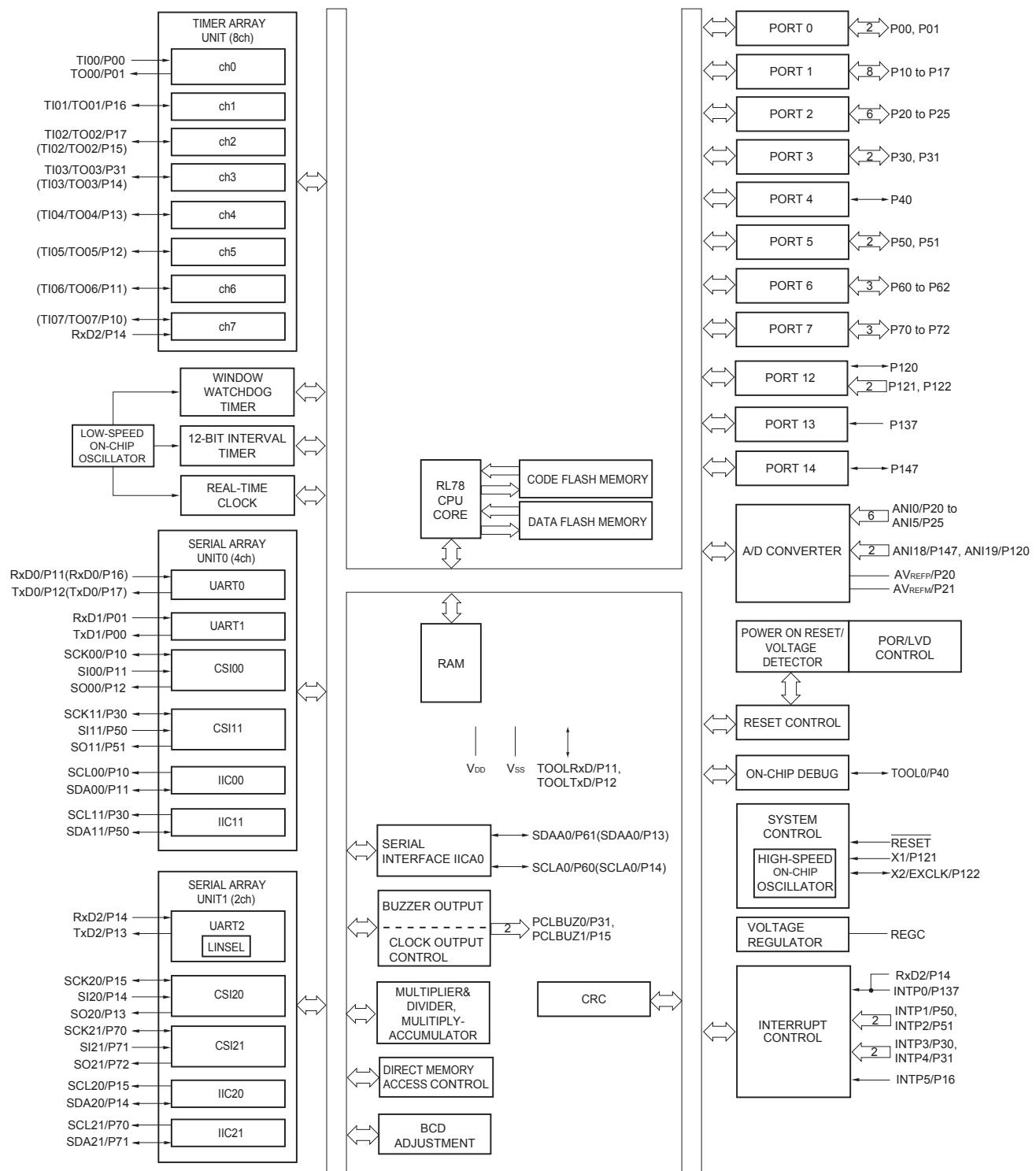


Caution Connect the REGC pin to V_{ss} via a capacitor (0.47 to 1 μ F).

Remarks 1. For pin identification, see **1.4 Pin Identification**.

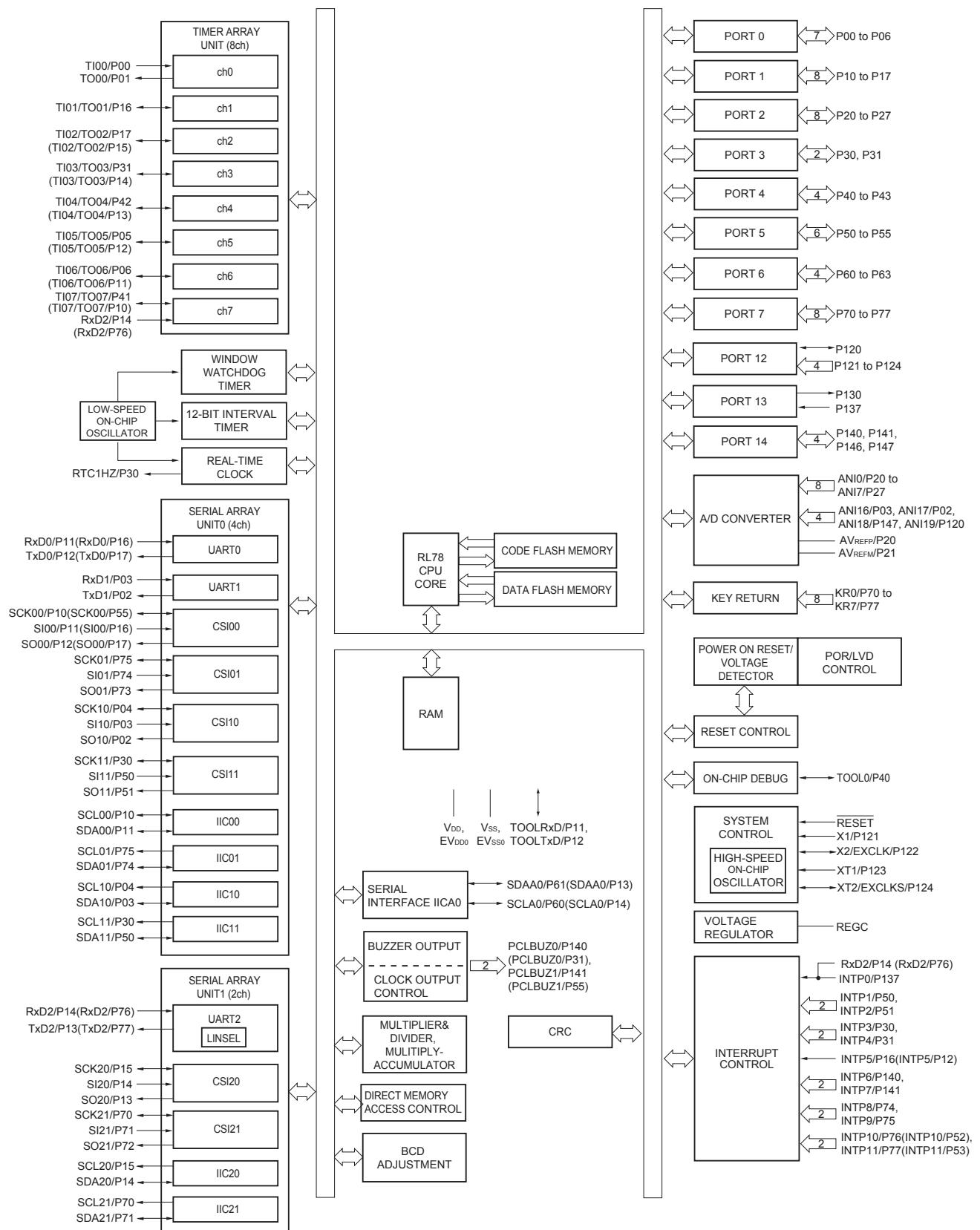
2. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.5.6 36-pin products



Remark Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.5.11 64-pin products



Remark Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

(3) 128-pin products, and flash ROM: 384 to 512 KB of 44- to 100-pin products

 $(T_A = -40$ to $+85^\circ\text{C}$, $1.6 \text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5 \text{ V}$, $V_{ss} = EV_{ss0} = EV_{ss1} = 0 \text{ V}$) (1/2)

| Parameter | Symbol | Conditions | | | | | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|-----------|--|---|------------------|--------------------------|--|------|------|------|---------------|
| Supply current ^{Note 1} | I_{DD1} | Operating mode HS (high-speed main) mode ^{Note 5} | $f_{IH} = 32 \text{ MHz}$ ^{Note 3} | Basic operation | $V_{DD} = 5.0 \text{ V}$ | | 2.6 | | | mA |
| | | | | | $V_{DD} = 3.0 \text{ V}$ | | 2.6 | | | mA |
| | | | $f_{IH} = 24 \text{ MHz}$ ^{Note 3} | Normal operation | $V_{DD} = 5.0 \text{ V}$ | | 6.1 | 9.5 | | mA |
| | | | | | $V_{DD} = 3.0 \text{ V}$ | | 6.1 | 9.5 | | mA |
| | | LS (low-speed main) mode ^{Note 5} | $f_{IH} = 16 \text{ MHz}$ ^{Note 3} | Normal operation | $V_{DD} = 5.0 \text{ V}$ | | 3.5 | 5.3 | | mA |
| | | | | | $V_{DD} = 3.0 \text{ V}$ | | 3.5 | 5.3 | | mA |
| | | LV (low-voltage main) mode ^{Note 5} | $f_{IH} = 8 \text{ MHz}$ ^{Note 3} | Normal operation | $V_{DD} = 3.0 \text{ V}$ | | 1.5 | 2.3 | | mA |
| | | | | | $V_{DD} = 2.0 \text{ V}$ | | 1.5 | 2.3 | | mA |
| | | HS (high-speed main) mode ^{Note 5} | $f_{MX} = 20 \text{ MHz}$ ^{Note 2} , $V_{DD} = 5.0 \text{ V}$ | Normal operation | Square wave input | | 3.9 | 6.1 | | mA |
| | | | | | Resonator connection | | 4.1 | 6.3 | | mA |
| | | | $f_{MX} = 20 \text{ MHz}$ ^{Note 2} , $V_{DD} = 3.0 \text{ V}$ | Normal operation | Square wave input | | 3.9 | 6.1 | | mA |
| | | | | | Resonator connection | | 4.1 | 6.3 | | mA |
| | | | $f_{MX} = 10 \text{ MHz}$ ^{Note 2} , $V_{DD} = 5.0 \text{ V}$ | Normal operation | Square wave input | | 2.5 | 3.7 | | mA |
| | | | | | Resonator connection | | 2.5 | 3.7 | | mA |
| | | LS (low-speed main) mode ^{Note 5} | $f_{MX} = 8 \text{ MHz}$ ^{Note 2} , $V_{DD} = 3.0 \text{ V}$ | Normal operation | Square wave input | | 1.4 | 2.2 | | mA |
| | | | | | Resonator connection | | 1.4 | 2.2 | | mA |
| | | | $f_{MX} = 8 \text{ MHz}$ ^{Note 2} , $V_{DD} = 2.0 \text{ V}$ | Normal operation | Square wave input | | 1.4 | 2.2 | | mA |
| | | | | | Resonator connection | | 1.4 | 2.2 | | mA |
| | | Subsystem clock operation | $f_{SUB} = 32.768 \text{ kHz}$ ^{Note 4} $T_A = -40^\circ\text{C}$ | Normal operation | Square wave input | | 5.4 | 6.5 | | μA |
| | | | | | Resonator connection | | 5.5 | 6.6 | | μA |
| | | | $f_{SUB} = 32.768 \text{ kHz}$ ^{Note 4} $T_A = +25^\circ\text{C}$ | Normal operation | Square wave input | | 5.5 | 6.5 | | μA |
| | | | | | Resonator connection | | 5.6 | 6.6 | | μA |
| | | | $f_{SUB} = 32.768 \text{ kHz}$ ^{Note 4} $T_A = +50^\circ\text{C}$ | Normal operation | Square wave input | | 5.6 | 9.4 | | μA |
| | | | | | Resonator connection | | 5.7 | 9.5 | | μA |
| | | | $f_{SUB} = 32.768 \text{ kHz}$ ^{Note 4} $T_A = +70^\circ\text{C}$ | Normal operation | Square wave input | | 5.9 | 12.0 | | μA |
| | | | | | Resonator connection | | 6.0 | 12.1 | | μA |
| | | | $f_{SUB} = 32.768 \text{ kHz}$ ^{Note 4} $T_A = +85^\circ\text{C}$ | Normal operation | Square wave input | | 6.6 | 16.3 | | μA |
| | | | | | Resonator connection | | 6.7 | 16.4 | | μA |

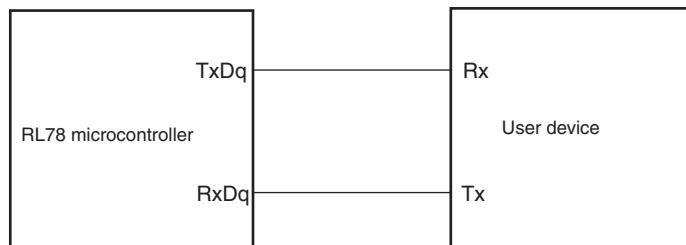
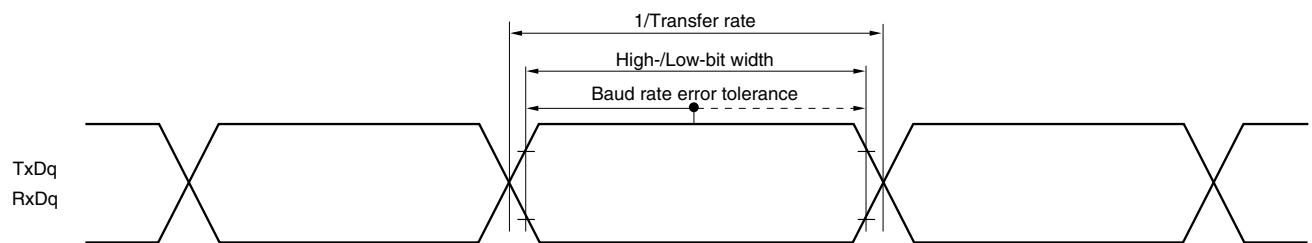
(Notes and Remarks are listed on the next page.)

2.4 AC Characteristics

(TA = -40 to +85°C, 1.6 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V)

| Items | Symbol | Conditions | | | MIN. | TYP. | MAX. | Unit |
|--|---------------------------------------|--|-----------------------------------|---------------------------------|------------------------|------|------|--------------------|
| Instruction cycle (minimum instruction execution time) | TCY | Main system clock (f _{MAIN}) operation | HS (high-speed main) mode | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0.03125 | | 1 | μs |
| | | | | 2.4 V ≤ V _{DD} < 2.7 V | 0.0625 | | 1 | μs |
| | | | LS (low-speed main) mode | 1.8 V ≤ V _{DD} ≤ 5.5 V | 0.125 | | 1 | μs |
| | | | LV (low-voltage main) mode | 1.6 V ≤ V _{DD} ≤ 5.5 V | 0.25 | | 1 | μs |
| | | Subsystem clock (f _{SUB}) operation | | 1.8 V ≤ V _{DD} ≤ 5.5 V | 28.5 | 30.5 | 31.3 | μs |
| | | In the self programming mode | HS (high-speed main) mode | 2.7 V ≤ V _{DD} ≤ 5.5 V | 0.03125 | | 1 | μs |
| | | | | 2.4 V ≤ V _{DD} < 2.7 V | 0.0625 | | 1 | μs |
| | | | LS (low-speed main) mode | 1.8 V ≤ V _{DD} ≤ 5.5 V | 0.125 | | 1 | μs |
| | | | LV (low-voltage main) mode | 1.6 V ≤ V _{DD} ≤ 5.5 V | 0.25 | | 1 | μs |
| External system clock frequency | f _{EX} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ V _{DD} < 2.7 V | | | 1.0 | | 16.0 | MHz |
| | | 1.8 V ≤ V _{DD} < 2.4 V | | | 1.0 | | 8.0 | MHz |
| | | 1.6 V ≤ V _{DD} < 1.8 V | | | 1.0 | | 4.0 | MHz |
| | f _{EXS} | | | | 32 | | 35 | kHz |
| External system clock input high-level width, low-level width | t _{EXH} , t _{EXL} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | | 24 | | | ns |
| | | 2.4 V ≤ V _{DD} < 2.7 V | | | 30 | | | ns |
| | | 1.8 V ≤ V _{DD} < 2.4 V | | | 60 | | | ns |
| | | 1.6 V ≤ V _{DD} < 1.8 V | | | 120 | | | ns |
| | t _{EXHS} , t _{EXLS} | | | | 13.7 | | | μs |
| TI00 to TI07, TI10 to TI17 input high-level width, low-level width | t _{TIH} , t _{TL} | | | | 1/f _{MCK} +10 | | | ns ^{Note} |
| TO00 to TO07, TO10 to TO17 output frequency | f _{TO} | HS (high-speed main) mode | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | | | 16 | MHz |
| | | | 2.7 V ≤ EV _{DD0} < 4.0 V | | | | 8 | MHz |
| | | | 1.8 V ≤ EV _{DD0} < 2.7 V | | | | 4 | MHz |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | | | 2 | MHz |
| | | LS (low-speed main) mode | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | | | 4 | MHz |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | | | 2 | MHz |
| | | LV (low-voltage main) mode | 1.6 V ≤ EV _{DD0} ≤ 5.5 V | | | | 2 | MHz |
| | | HS (high-speed main) mode | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | | | 16 | MHz |
| | | | 2.7 V ≤ EV _{DD0} < 4.0 V | | | | 8 | MHz |
| | | | 1.8 V ≤ EV _{DD0} < 2.7 V | | | | 4 | MHz |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | | | 2 | MHz |
| PCLBUZ0, PCLBUZ1 output frequency | f _{PCL} | LS (low-speed main) mode | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | | | 4 | MHz |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | | | 2 | MHz |
| | | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | | | 4 | MHz |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | | | 2 | MHz |
| | | LV (low-voltage main) mode | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | | | 4 | MHz |
| | | | 1.6 V ≤ EV _{DD0} < 1.8 V | | | | 2 | MHz |
| | | | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | | | | 4 | MHz |
| Interrupt input high-level width, low-level width | t _{INTH} , t _{INTL} | INTP0 | 1.6 V ≤ V _{DD} ≤ 5.5 V | 1 | | | | μs |
| | | INTP1 to INTP11 | 1.6 V ≤ EV _{DD0} ≤ 5.5 V | 1 | | | | μs |
| | | KR0 to KR7 | 1.8 V ≤ EV _{DD0} ≤ 5.5 V | 250 | | | | ns |
| Key interrupt input low-level width | | | 1.6 V ≤ EV _{DD0} < 1.8 V | 1 | | | | μs |
| t _{RSI} | | | | 10 | | | μs | |

(Note and Remark are listed on the next page.)

UART mode connection diagram (during communication at same potential)**UART mode bit width (during communication at same potential) (reference)**

Remarks 1. q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)

2. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

(9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)

($T_A = -40$ to $+85^\circ\text{C}$, $1.8 \text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5 \text{ V}$, $V_{SS} = EV_{SS0} = EV_{SS1} = 0 \text{ V}$) (1/2)

| Parameter | Symbol | Conditions | HS (high-speed main) Mode | | LS (low-speed main) Mode | | LV (low-voltage main) Mode | | Unit |
|-----------------------------------|-------------------|---|--------------------------------|------------------|--------------------------|------------------|----------------------------|------------------|------|
| | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCKp cycle time ^{Note 1} | t _{KCY2} | 4.0 V $\leq EV_{DD0} \leq 5.5$ V, 2.7 V $\leq V_b \leq 4.0$ V | 24 MHz $< f_{MCK}$ | 14/ f_{MCK} | — | — | — | — | ns |
| | | | 20 MHz $< f_{MCK} \leq 24$ MHz | 12/ f_{MCK} | — | — | — | — | ns |
| | | | 8 MHz $< f_{MCK} \leq 20$ MHz | 10/ f_{MCK} | — | — | — | — | ns |
| | | | 4 MHz $< f_{MCK} \leq 8$ MHz | 8/ f_{MCK} | — | 16/ f_{MCK} | — | — | ns |
| | | | $f_{MCK} \leq 4$ MHz | 6/ f_{MCK} | — | 10/ f_{MCK} | — | 10/ f_{MCK} | ns |
| | | 2.7 V $\leq EV_{DD0} < 4.0$ V, 2.3 V $\leq V_b \leq 2.7$ V | 24 MHz $< f_{MCK}$ | 20/ f_{MCK} | — | — | — | — | ns |
| | | | 20 MHz $< f_{MCK} \leq 24$ MHz | 16/ f_{MCK} | — | — | — | — | ns |
| | | | 16 MHz $< f_{MCK} \leq 20$ MHz | 14/ f_{MCK} | — | — | — | — | ns |
| | | | 8 MHz $< f_{MCK} \leq 16$ MHz | 12/ f_{MCK} | — | — | — | — | ns |
| | | | $f_{MCK} \leq 4$ MHz | 8/ f_{MCK} | — | 16/ f_{MCK} | — | — | ns |
| | | 1.8 V $\leq EV_{DD0} < 3.3$ V, 1.6 V $\leq V_b \leq 2.0$ V ^{Note 2} | 24 MHz $< f_{MCK}$ | 48/ f_{MCK} | — | — | — | — | ns |
| | | | 20 MHz $< f_{MCK} \leq 24$ MHz | 36/ f_{MCK} | — | — | — | — | ns |
| | | | 16 MHz $< f_{MCK} \leq 20$ MHz | 32/ f_{MCK} | — | — | — | — | ns |
| | | | 8 MHz $< f_{MCK} \leq 16$ MHz | 26/ f_{MCK} | — | — | — | — | ns |
| | | | $f_{MCK} \leq 4$ MHz | 16/ f_{MCK} | — | 16/ f_{MCK} | — | — | ns |

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)

(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode) (1/2) $(T_A = -40$ to $+85^\circ\text{C}$, $1.8 \text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5 \text{ V}$, $V_{SS} = EV_{SS0} = EV_{SS1} = 0 \text{ V}$)

| Parameter | Symbol | Conditions | HS (high-speed main) Mode | | LS (low-speed main) Mode | | LV (low-voltage main) Mode | | Unit |
|---------------------------------------|-------------------|--|---------------------------|-------------------------------|--------------------------|------------------------------|----------------------------|------------------------------|------|
| | | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | |
| SCL _r clock frequency | f _{SCL} | 4.0 V \leq EV _{DD0} \leq 5.5 V, 2.7 V \leq V _b \leq 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | | 1000 <small>Note 1</small> | | 300 <small>Note 1</small> | | 300 <small>Note 1</small> | kHz |
| | | 2.7 V \leq EV _{DD0} < 4.0 V, 2.3 V \leq V _b \leq 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | | 1000 <small>Note 1</small> | | 300 <small>Note 1</small> | | 300 <small>Note 1</small> | kHz |
| | | 4.0 V \leq EV _{DD0} \leq 5.5 V, 2.7 V \leq V _b \leq 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | | 400 <small>Note 1</small> | | 300 <small>Note 1</small> | | 300 <small>Note 1</small> | kHz |
| | | 2.7 V \leq EV _{DD0} < 4.0 V, 2.3 V \leq V _b \leq 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | | 400 <small>Note 1</small> | | 300 <small>Note 1</small> | | 300 <small>Note 1</small> | kHz |
| | | 1.8 V \leq EV _{DD0} < 3.3 V, 1.6 V \leq V _b \leq 2.0 V <small>Note 2</small> , C _b = 100 pF, R _b = 5.5 kΩ | | 300 <small>Note 1</small> | | 300 <small>Note 1</small> | | 300 <small>Note 1</small> | kHz |
| Hold time when SCL _r = "L" | t _{LOW} | 4.0 V \leq EV _{DD0} \leq 5.5 V, 2.7 V \leq V _b \leq 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 475 | | 1550 | | 1550 | | ns |
| | | 2.7 V \leq EV _{DD0} < 4.0 V, 2.3 V \leq V _b \leq 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 475 | | 1550 | | 1550 | | ns |
| | | 4.0 V \leq EV _{DD0} \leq 5.5 V, 2.7 V \leq V _b \leq 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 1150 | | 1550 | | 1550 | | ns |
| | | 2.7 V \leq EV _{DD0} < 4.0 V, 2.3 V \leq V _b \leq 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 1150 | | 1550 | | 1550 | | ns |
| | | 1.8 V \leq EV _{DD0} < 3.3 V, 1.6 V \leq V _b \leq 2.0 V <small>Note 2</small> , C _b = 100 pF, R _b = 5.5 kΩ | 1550 | | 1550 | | 1550 | | ns |
| Hold time when SCL _r = "H" | t _{HIGH} | 4.0 V \leq EV _{DD0} \leq 5.5 V, 2.7 V \leq V _b \leq 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 245 | | 610 | | 610 | | ns |
| | | 2.7 V \leq EV _{DD0} < 4.0 V, 2.3 V \leq V _b \leq 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 200 | | 610 | | 610 | | ns |
| | | 4.0 V \leq EV _{DD0} \leq 5.5 V, 2.7 V \leq V _b \leq 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 675 | | 610 | | 610 | | ns |
| | | 2.7 V \leq EV _{DD0} < 4.0 V, 2.3 V \leq V _b \leq 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 600 | | 610 | | 610 | | ns |
| | | 1.8 V \leq EV _{DD0} < 3.3 V, 1.6 V \leq V _b \leq 2.0 V <small>Note 2</small> , C _b = 100 pF, R _b = 5.5 kΩ | 610 | | 610 | | 610 | | ns |

2.6 Analog Characteristics

2.6.1 A/D converter characteristics

Classification of A/D converter characteristics

| Input channel | Reference Voltage | | |
|--|---|---|---|
| | Reference voltage (+) = AV_{REFP} | Reference voltage (+) = V_{DD} | Reference voltage (+) = V_{BGR} |
| Reference voltage (-) = AV_{REFM} | Reference voltage (-) = V_{SS} | Reference voltage (-) = AV_{REFM} | Reference voltage (-) = AV_{REFM} |
| ANI0 to ANI14 | Refer to 2.6.1 (1). | Refer to 2.6.1 (3). | Refer to 2.6.1 (4). |
| ANI16 to ANI26 | Refer to 2.6.1 (2). | | |
| Internal reference voltage Temperature sensor output voltage | Refer to 2.6.1 (1). | | — |

(1) When reference voltage (+) = AV_{REFP} /ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV_{REFM} /ANI1 (ADREFM = 1), target pin : ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

($T_A = -40$ to $+85^\circ\text{C}$, $1.6 \text{ V} \leq \text{AV}_{\text{REFP}} \leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$, $\text{V}_{\text{SS}} = 0 \text{ V}$, Reference voltage (+) = AV_{REFP} , Reference voltage (-) = $\text{AV}_{\text{REFM}} = 0 \text{ V}$)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|-------------------|---|---|--------|--|---------------------------|---------------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error ^{Note 1} | AINL | 10-bit resolution $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}}$ ^{Note 3} | 1.8 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ | | 1.2 | ± 3.5 | LSB |
| | | | 1.6 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ ^{Note 4} | | 1.2 | ± 7.0 | LSB |
| Conversion time | t _{CONV} | 10-bit resolution Target pin: ANI2 to ANI14 | 3.6 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 2.125 | | 39 | μs |
| | | | 2.7 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 3.1875 | | 39 | μs |
| | | | 1.8 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 17 | | 39 | μs |
| | | | 1.6 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 57 | | 95 | μs |
| | t _{CONV} | 10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode) | 3.6 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 2.375 | | 39 | μs |
| | | | 2.7 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 3.5625 | | 39 | μs |
| | | | 2.4 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$ | 17 | | 39 | μs |
| | | | | | | | |
| Zero-scale error ^{Notes 1, 2} | E _{zs} | 10-bit resolution $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}}$ ^{Note 3} | 1.8 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ | | | ± 0.25 | %FSR |
| | | | 1.6 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ ^{Note 4} | | | ± 0.50 | %FSR |
| Full-scale error ^{Notes 1, 2} | E _{fs} | 10-bit resolution $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}}$ ^{Note 3} | 1.8 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ | | | ± 0.25 | %FSR |
| | | | 1.6 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ ^{Note 4} | | | ± 0.50 | %FSR |
| Integral linearity error ^{Note 1} | ILE | 10-bit resolution $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}}$ ^{Note 3} | 1.8 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ | | | ± 2.5 | LSB |
| | | | 1.6 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ ^{Note 4} | | | ± 5.0 | LSB |
| Differential linearity error ^{Note 1} | DLE | 10-bit resolution $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}}$ ^{Note 3} | 1.8 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ | | | ± 1.5 | LSB |
| | | | 1.6 V $\leq \text{AV}_{\text{REFP}} \leq 5.5 \text{ V}$ ^{Note 4} | | | ± 2.0 | LSB |
| Analog input voltage | V _{AIN} | ANI2 to ANI14 | | 0 | | AV_{REFP} | V |
| | | Internal reference voltage (2.4 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$, HS (high-speed main) mode) | | | V_{BGR} ^{Note 5} | | V |
| | | Temperature sensor output voltage (2.4 V $\leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}$, HS (high-speed main) mode) | | | V_{TMPS25} ^{Note 5} | | V |

(Notes are listed on the next page.)

3.3 DC Characteristics

3.3.1 Pin characteristics

(TA = -40 to +105°C, 2.4 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V) (1/5)

| Items | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|------------------|--|-----------------------------------|------|------------------------|------|
| Output current, high ^{Note 1} | I _{OH1} | Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147 | 2.4 V ≤ EV _{DD0} ≤ 5.5 V | | -3.0 ^{Note 2} | mA |
| | | Total of P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty ≤ 70% ^{Note 3}) | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | -30.0 | mA |
| | | | 2.7 V ≤ EV _{DD0} < 4.0 V | | -10.0 | mA |
| | | | 2.4 V ≤ EV _{DD0} < 2.7 V | | -5.0 | mA |
| | | Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147 (When duty ≤ 70% ^{Note 3}) | 4.0 V ≤ EV _{DD0} ≤ 5.5 V | | -30.0 | mA |
| | | | 2.7 V ≤ EV _{DD0} < 4.0 V | | -19.0 | mA |
| | | | 2.4 V ≤ EV _{DD0} < 2.7 V | | -10.0 | mA |
| | | Total of all pins (When duty ≤ 70% ^{Note 3}) | 2.4 V ≤ EV _{DD0} ≤ 5.5 V | | -60.0 | mA |
| | I _{OH2} | Per pin for P20 to P27, P150 to P156 | 2.4 V ≤ V _{DD} ≤ 5.5 V | | -0.1 ^{Note 2} | mA |
| | | Total of all pins (When duty ≤ 70% ^{Note 3}) | 2.4 V ≤ V _{DD} ≤ 5.5 V | | -1.5 | mA |

Notes 1. Value of current at which the device operation is guaranteed even if the current flows from the EV_{DD0}, EV_{DD1}, V_{DD} pins to an output pin.

2. Do not exceed the total current value.

3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I_{OH} × 0.7)/(n × 0.01)

<Example> Where n = 80% and I_{OH} = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

Caution P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{SS0} = EV_{SS1} = 0 V) (4/5)

| Items | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------|------------------|--|--|-------------------------|------|------|
| Output voltage, high | V _{OH1} | P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147 | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, I _{OH1} = -3.0 mA | EV _{DD0} – 0.7 | | V |
| | | | 2.7 V ≤ EV _{DD0} ≤ 5.5 V, I _{OH1} = -2.0 mA | EV _{DD0} – 0.6 | | V |
| | | | 2.4 V ≤ EV _{DD0} ≤ 5.5 V, I _{OH1} = -1.5 mA | EV _{DD0} – 0.5 | | V |
| | V _{OH2} | P20 to P27, P150 to P156 | 2.4 V ≤ V _{DD} ≤ 5.5 V, I _{OH2} = -100 μA | V _{DD} – 0.5 | | V |
| Output voltage, low | V _{OL1} | P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147 | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL1} = 8.5 mA | | 0.7 | V |
| | | | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL1} = 3.0 mA | | 0.6 | V |
| | | | 2.7 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL1} = 1.5 mA | | 0.4 | V |
| | | | 2.4 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL1} = 0.6 mA | | 0.4 | V |
| | V _{OL2} | P20 to P27, P150 to P156 | 2.4 V ≤ V _{DD} ≤ 5.5 V, I _{OL2} = 400 μA | | 0.4 | V |
| | V _{OL3} | P60 to P63 | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL3} = 15.0 mA | | 2.0 | V |
| | | | 4.0 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL3} = 5.0 mA | | 0.4 | V |
| | | | 2.7 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL3} = 3.0 mA | | 0.4 | V |
| | | | 2.4 V ≤ EV _{DD0} ≤ 5.5 V, I _{OL3} = 2.0 mA | | 0.4 | V |

Caution P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

3.6 Analog Characteristics

3.6.1 A/D converter characteristics

Classification of A/D converter characteristics

| Input channel | Reference Voltage | | |
|---|--|--|--|
| | Reference voltage (+) = AVREFP Reference voltage (-) = AVREFM | Reference voltage (+) = VDD Reference voltage (-) = Vss | Reference voltage (+) = VBGR Reference voltage (-) = AVREFM |
| ANI0 to ANI14 | Refer to 3.6.1 (1). | Refer to 3.6.1 (3). | Refer to 3.6.1 (4). |
| ANI16 to ANI26 | Refer to 3.6.1 (2). | | |
| Internal reference voltage Temperature sensor output voltage | Refer to 3.6.1 (1). | | — |

- (1) When reference voltage (+) = AVREFP/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin : ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +105°C, 2.4 V ≤ AVREFP ≤ VDD ≤ 5.5 V, Vss = 0 V, Reference voltage (+) = AVREFP, Reference voltage (-) = AVREFM = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|--------|--|------------------------|--------|---------------------------|--------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error ^{Note 1} | AINL | 10-bit resolution AVREFP = VDD ^{Note 3} | 2.4 V ≤ AVREFP ≤ 5.5 V | | 1.2 | ±3.5 | LSB |
| Conversion time | tCONV | 10-bit resolution Target pin: ANI2 to ANI14 | 3.6 V ≤ VDD ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ VDD ≤ 5.5 V | 3.1875 | | 39 | μs |
| | | | 2.4 V ≤ VDD ≤ 5.5 V | 17 | | 39 | μs |
| | | 10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode) | 3.6 V ≤ VDD ≤ 5.5 V | 2.375 | | 39 | μs |
| | | | 2.7 V ≤ VDD ≤ 5.5 V | 3.5625 | | 39 | μs |
| | | | 2.4 V ≤ VDD ≤ 5.5 V | 17 | | 39 | μs |
| Zero-scale error ^{Notes 1, 2} | Ezs | 10-bit resolution AVREFP = VDD ^{Note 3} | 2.4 V ≤ AVREFP ≤ 5.5 V | | | ±0.25 | %FSR |
| Full-scale error ^{Notes 1, 2} | Efs | 10-bit resolution AVREFP = VDD ^{Note 3} | 2.4 V ≤ AVREFP ≤ 5.5 V | | | ±0.25 | %FSR |
| Integral linearity error ^{Note 1} | ILE | 10-bit resolution AVREFP = VDD ^{Note 3} | 2.4 V ≤ AVREFP ≤ 5.5 V | | | ±2.5 | LSB |
| Differential linearity error ^{Note 1} | DLE | 10-bit resolution AVREFP = VDD ^{Note 3} | 2.4 V ≤ AVREFP ≤ 5.5 V | | | ±1.5 | LSB |
| Analog input voltage | VAIN | ANI2 to ANI14 | | 0 | | AVREFP | V |
| | | Internal reference voltage output (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode) | | | VBGR ^{Note 4} | | V |
| | | Temperature sensor output voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode) | | | VTMPS25 ^{Note 4} | | V |

(Notes are listed on the next page.)

- (2) When reference voltage (+) = $AV_{REFP}/ANI0$ (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = $AV_{REFM}/ANI1$ (ADREFM = 1), target pin : ANI16 to ANI26

(TA = -40 to +105°C, 2.4 V ≤ EV_{DD0} = EV_{DD1} ≤ V_{DD} ≤ 5.5 V, 2.4 V ≤ AV_{REFP} ≤ V_{DD} ≤ 5.5 V, V_{SS} = EV_{VSS0} = EV_{VSS1} = 0 V, Reference voltage (+) = AV_{REFP}, Reference voltage (-) = AV_{REFM} = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---|-------------------|---|------------------------------------|--------|------|--|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error ^{Note 1} | AINL | 10-bit resolution EV _{DD0} ≤ AV _{REFP} = V _{DD} ^{Notes 3, 4} | 2.4 V ≤ AV _{REFP} ≤ 5.5 V | | 1.2 | ±5.0 | LSB |
| Conversion time | t _{CONV} | 10-bit resolution Target pin : ANI16 to ANI26 | 3.6 V ≤ V _{DD} ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 3.1875 | | 39 | μs |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 17 | | 39 | μs |
| Zero-scale error ^{Notes 1, 2} | E _{ZS} | 10-bit resolution EV _{DD0} ≤ AV _{REFP} = V _{DD} ^{Notes 3, 4} | 2.4 V ≤ AV _{REFP} ≤ 5.5 V | | | ±0.35 | %FSR |
| Full-scale error ^{Notes 1, 2} | E _{FS} | 10-bit resolution EV _{DD0} ≤ AV _{REFP} = V _{DD} ^{Notes 3, 4} | 2.4 V ≤ AV _{REFP} ≤ 5.5 V | | | ±0.35 | %FSR |
| Integral linearity error ^{Note 1} | ILE | 10-bit resolution EV _{DD0} ≤ AV _{REFP} = V _{DD} ^{Notes 3, 4} | 2.4 V ≤ AV _{REFP} ≤ 5.5 V | | | ±3.5 | LSB |
| Differential linearity error <small>Note 1</small> | DLE | 10-bit resolution EV _{DD0} ≤ AV _{REFP} = V _{DD} ^{Notes 3, 4} | 2.4 V ≤ AV _{REFP} ≤ 5.5 V | | | ±2.0 | LSB |
| Analog input voltage | V _{AiN} | ANI16 to ANI26 | | 0 | | AV _{REFP} and EV _{DD0} | V |

Notes 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When AV_{REFP} < V_{DD}, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV_{REFP} = V_{DD}.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV_{REFP} = V_{DD}.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV_{REFP} = V_{DD}.

4. When AV_{REFP} < EV_{DD0} ≤ V_{DD}, the MAX. values are as follows.

Overall error: Add ±4.0 LSB to the MAX. value when AV_{REFP} = V_{DD}.

Zero-scale error/Full-scale error: Add ±0.20%FSR to the MAX. value when AV_{REFP} = V_{DD}.

Integral linearity error/ Differential linearity error: Add ±2.0 LSB to the MAX. value when AV_{REFP} = V_{DD}.

R5F100LCABG, R5F100LDABG, R5F100LEABG, R5F100LFABG, R5F100LGABG, R5F100LHABG,

R5F100LJABG

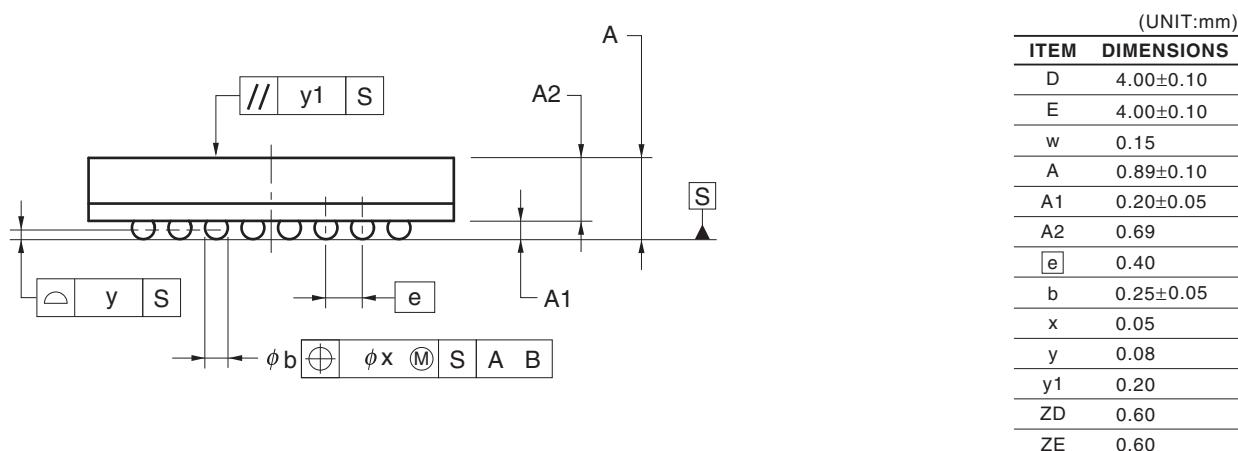
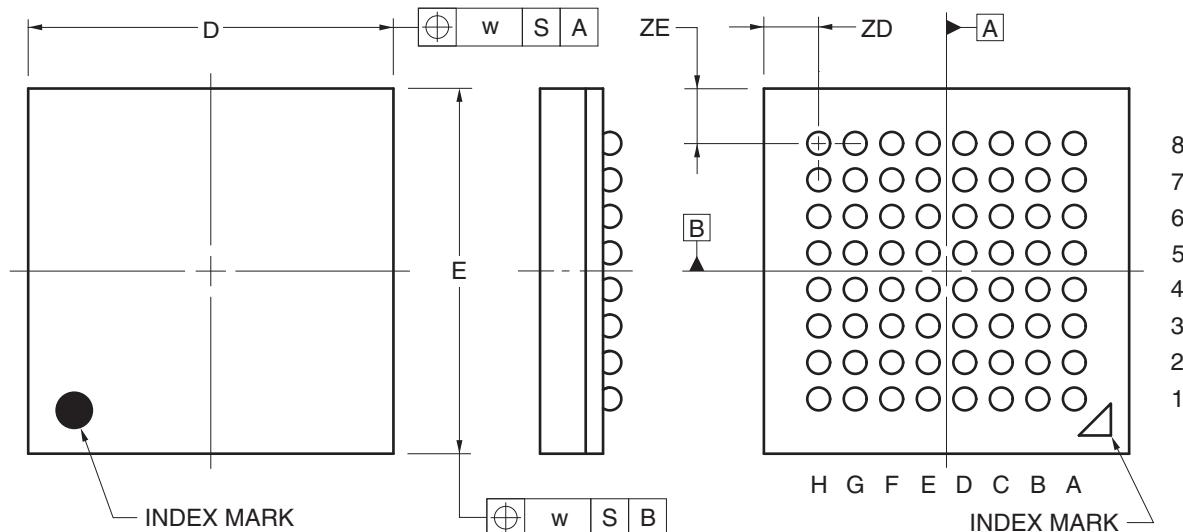
R5F101LCABG, R5F101LDABG, R5F101LEABG, R5F101LFABG, R5F101LGABG, R5F101LHABG,

R5F101LJABG

R5F100LCGBG, R5F100LDGBG, R5F100LEGBG, R5F100LFGBG, R5F100LGGBG, R5F100LHGBG,

R5F100LJGBG

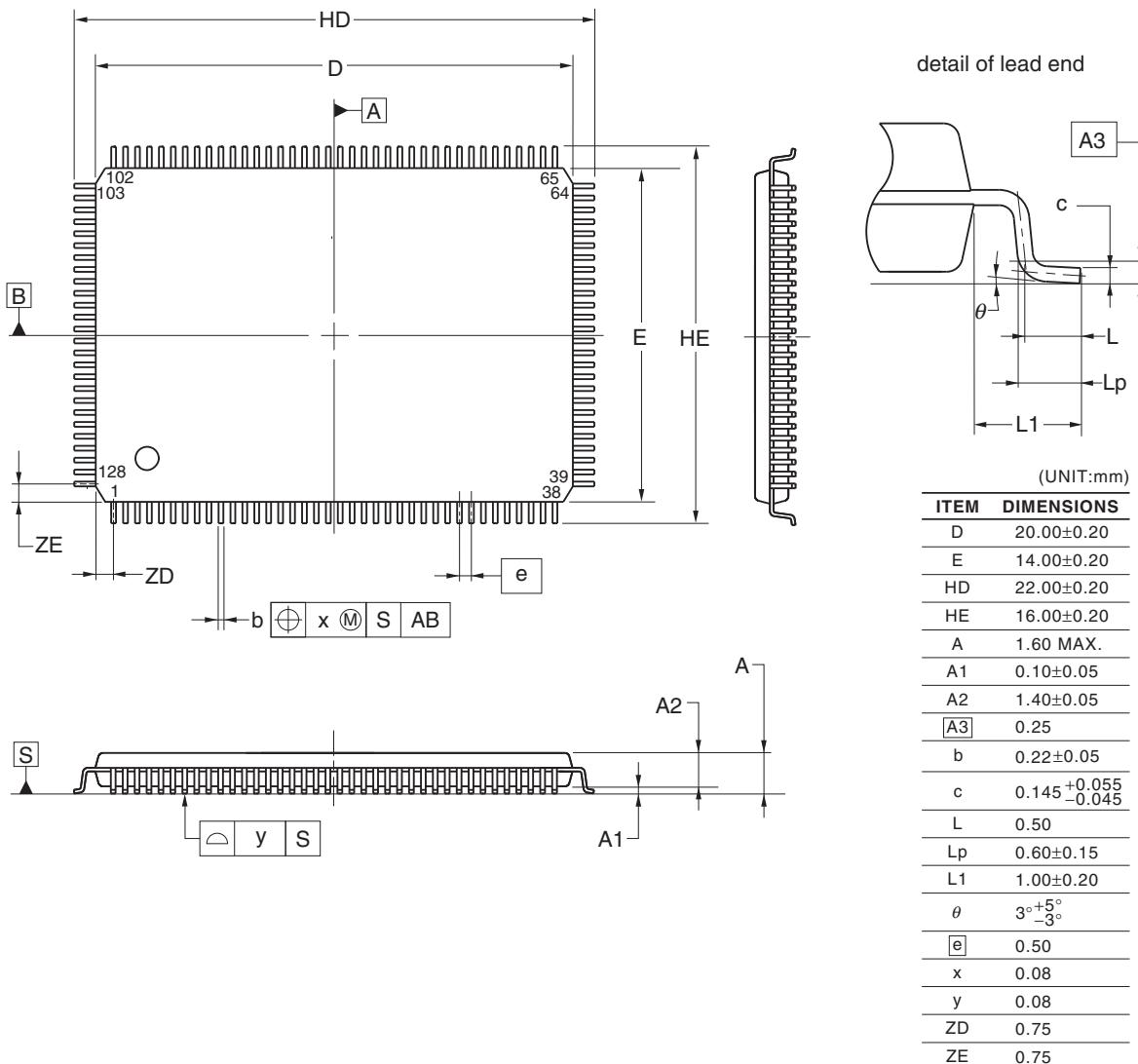
| JEITA Package Code | RENESAS Code | Previous Code | MASS (TYP.) [g] |
|--------------------|--------------|----------------|-----------------|
| P-VFBGA64-4x4-0.40 | PVBG0064LA-A | P64F1-40-AA2-2 | 0.03 |



4.14 128-pin Products

R5F100SHAFB, R5F100SJAFB, R5F100SKAFB, R5F100SLAFB
 R5F101SHAFB, R5F101SJAFB, R5F101SKAFB, R5F101SLAFB
 R5F100SHDFB, R5F100SJDFB, R5F100SKDFB, R5F100SLDFB
 R5F101SHDFB, R5F101SJDFB, R5F101SKDFB, R5F101SLDFB

| JEITA Package Code | RENESAS Code | Previous Code | MASS (TYP.) [g] |
|-----------------------|--------------|-----------------|-----------------|
| P-LFQFP128-14x20-0.50 | PLQP0128KD-A | P128GF-50-GBP-1 | 0.92 |



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